

MT3S35T

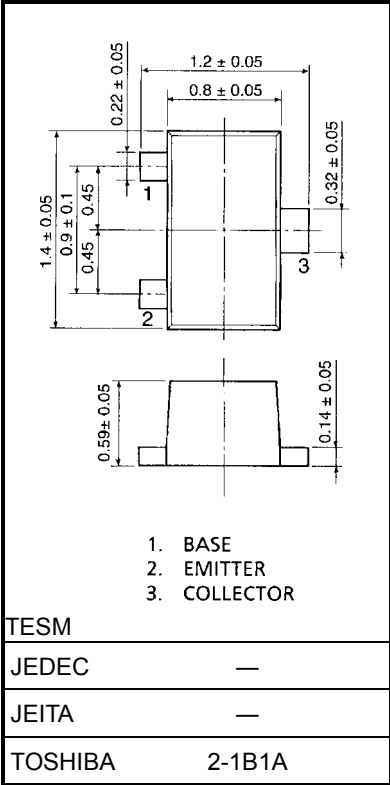
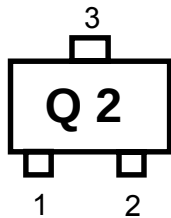
VCO OSCILLETOR STAGE
UHF LOW NOISE AMPLIFIER APPLICATION

Unit: mm

FEATURES

- Low Noise Figure :NF=1.4dB (@f=2GHz)
- High Gain:|S21e|^2=13.0dB (@f=2GHz)

Marking



Weight:0.0022g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-Base voltage	V_{CBO}	8	V
Collector-Emitter voltage	V_{CEO}	4.5	V
Emitter-Base voltage	V_{EBO}	1.5	V
Collector-Current	I_C	24	mA
Base-Current	I_B	12	mA
Collector Power dissipation	P_C	100	mW
Junction temperature	T_j	150	°C
Storage temperature Range	T_{stg}	-55~150	°C

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Transition Frequency	f _T	V _{CE} =3V, I _C =10mA, f=2GHz	16	20	-	GHz
Insertion Gain	S _{21e} ² (1)	V _{CE} =3V, I _C =10mA, f=1GHz	16	18	-	dB
	S _{21e} ² (2)	V _{CE} =3V, I _C =10mA, f=2GHz	11	13	-	dB
Noise Figure	NF(1)	V _{CE} =3V, I _C =2mA, f=1GHz	-	1.1	-	dB
	NF(2)	V _{CE} =3V, I _C =2mA, f=2GHz	-	1.4	1.9	dB

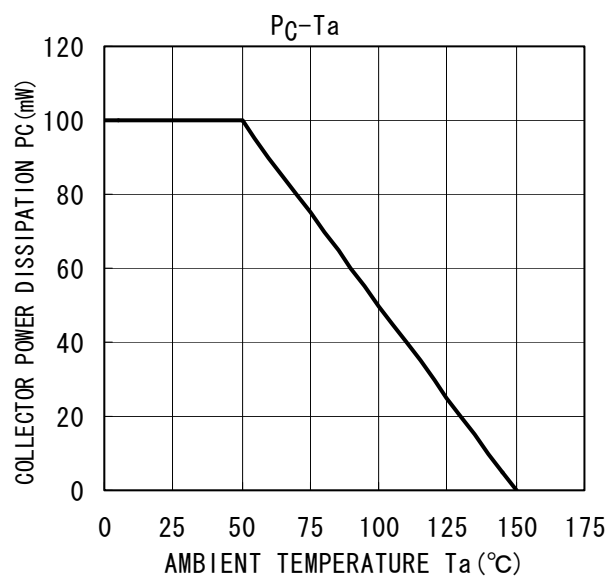
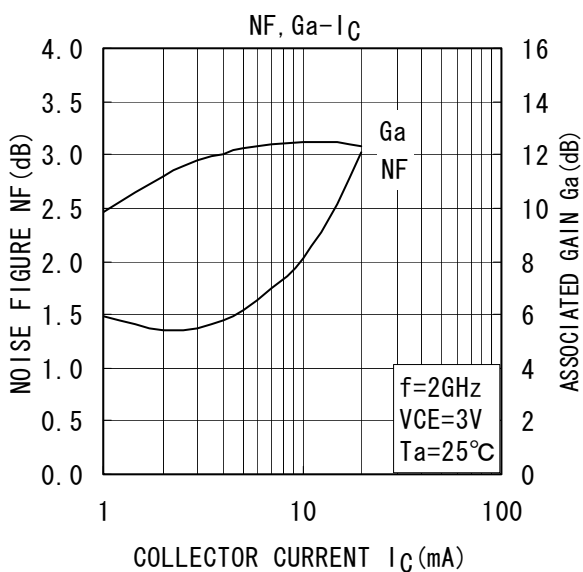
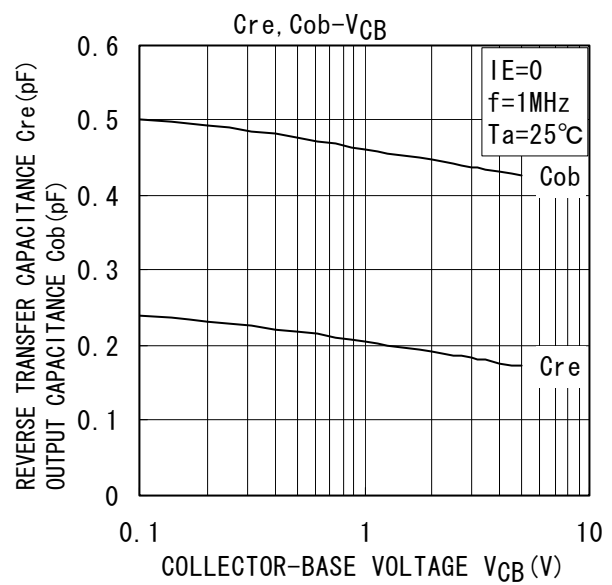
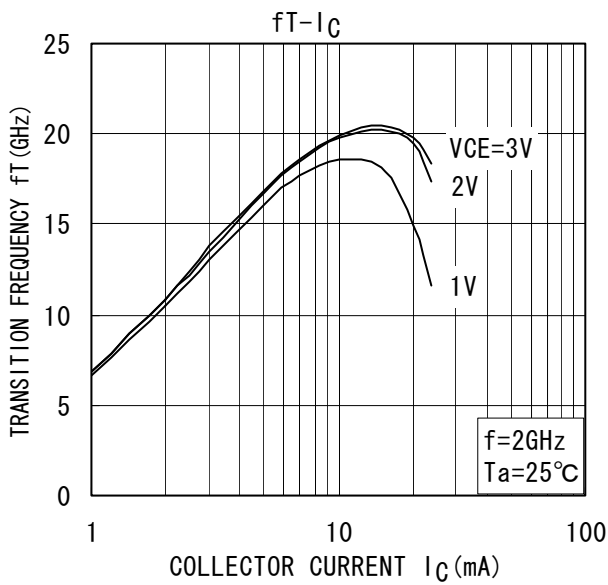
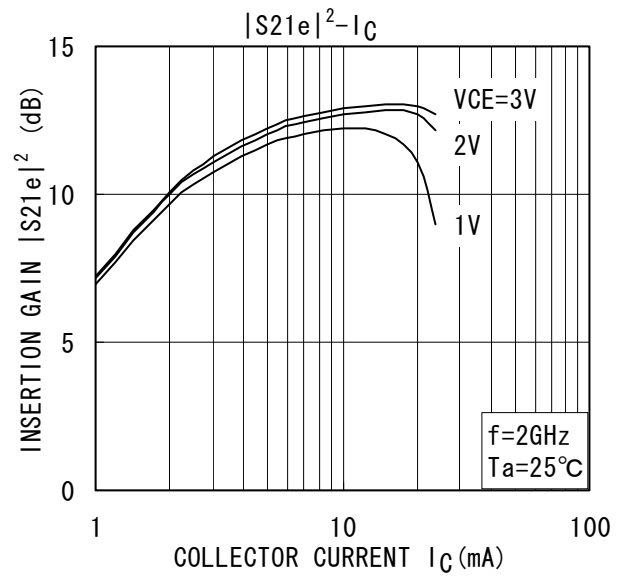
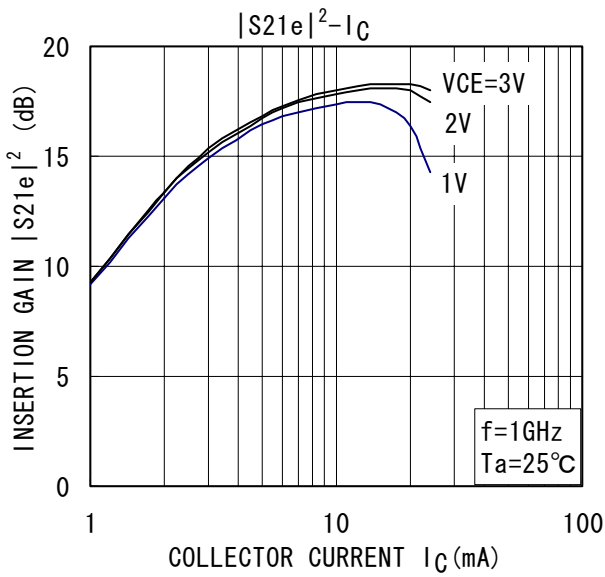
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector Cut-off Current	I _{CBO}	V _{CB} =8V, I _E =0	-	-	1	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =1V, I _C =0	-	-	1	μA
DC Current Gain	h _{FE}	V _{CE} =3V, I _C =10mA	70	-	140	-
Output Capacitance	C _{ob}	V _{CB} =1V, I _E =0, f=1MHz	-	0.46	0.75	pF
Reverse Transistor Capacitance	C _{re}	V _{CB} =1V, I _E =0, f=1MHz (Note 1)	-	0.21	0.4	pF

Note 1: C_{re} is measured by 3 terminal method with capacitance bridge.

Caution: This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.



RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.